NSN 5962-01-181-3104

Memory Microcircuit - Page 1 of 2



view Online at https://aerobasegroup.com/nsn/5962-01-161-3104
Body Length:
Between 1.185 inches and 1.215 inches
Body Width:
Between 0.568 inches and 0.588 inches
Body Height:
Between 0.075 inches and 0.085 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-30.0/+85.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5815-01-062-8194 communications terminal
Features Provided:
Monolithic
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Test Data Document:
80063-sm-a-915718 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization: Yes - demil/mli

NSN 5962-01-181-3104

Memory Microcircuit - Page 2 of 2



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